

### **NPN SMALL-SIGNAL TRANSISTOR IN SOT323**

### **Features**

- Ideally Suited for Automatic Insertion
- Complementary PNP Type: BC857BWQ
- For Switching and AF Amplifier Applications
- Totally Lead-Free & Fully RoHS Compliant (Notes 1 & 2)
- Halogen and Antimony Free. "Green" Device (Note 3)
- The BC846BWQ-BC847CWQ are suitable for automotive applications requiring specific change control; these parts are AEC-Q101 qualified, PPAP capable, and manufactured in IATF 16949 certified facilities.

https://www.diodes.com/quality/product-definitions/

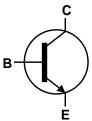
# **Mechanical Data**

- Package: SOT323
- Package Material: Molded Plastic, "Green" Molding Compound UL Flammability Classification Rating 94V-0
- Moisture Sensitivity: Level 1 per J-STD-020
- Terminals: Finish—Matte Tin Plated Leads, Solderable per MIL-STD-202, Method 208 ©3
- Weight: 0.006 grams (Approximate)

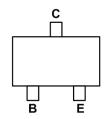
**SOT323** 



Top View



Device Symbol



Top View Pin-Out

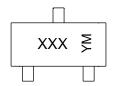
## **Ordering Information** (Note 4)

Part Number	Paakaga	Marking	Reel Size (inches)	Packing		
Part Number	Part Number Package N		Reel Size (Iliches)	Qty.	Carrier	
BC846BWQ-7-F	SOT323	K1R	7	3,000	Reel	
BC847BWQ-13-F	SOT323	K1R	13	10,000	Reel	
BC847CWQ-7-F	SOT323	K1M	7	3,000	Reel	

Notes:

- 1. No purposely added lead. Fully EU Directive 2002/95/EC (RoHS), 2011/65/EU (RoHS 2) & 2015/863/EU (RoHS 3) compliant.
- 2. See https://www.diodes.com/quality/lead-free/ for more information about Diodes Incorporated's definitions of Halogen- and Antimony-free, "Green" and Lead-free.
- 3. Halogen- and Antimony-free "Green" products are defined as those which contain <900ppm bromine, <900ppm chlorine (<1500ppm total Br + Cl) and <1000ppm antimony compounds.
- 4. For packaging details, go to our website at https://www.diodes.com/design/support/packaging/diodes-packaging/.

## **Marking Information**



XXX = Product Type Marking Code (Please See *Ordering Information*) YM = Date Code Marking

Y or  $\overline{Y}$  = Year (ex: L = 2024) M or  $\overline{M}$  = Month (ex: 2 = February)

#### Date Code Key

Year	2023	2024	2025	2026	2027	2028	2029	2030	2031	2032	2033	2034
Code	K	L	М	N	Р	R	S	Т	U	V	W	Х
Month	Jan	Feb	Mar	Apr	May	Jun	Jul	Aug	Sep	Oct	Nov	Dec



## Absolute Maximum Ratings (@TA = +25°C, unless otherwise specified.)

Chara	cteristic	Symbol	Value	Unit
Collector-Base Voltage	BC846BWQ	V	80	V
Collector-Base voltage	BC847BWQ/BC847CWQ	Vсво	50	V
Collector-Emitter Voltage	BC846BWQ	V	65	V
Collector-Emitter voltage	BC847BWQ/BC847CWQ	V <sub>CEO</sub>	45	V
Emitter-Base Voltage		VEBO	6	V
Continuous Collector Current		Ic	100	mA
Peak Collector Current		Ісм	200	mA
Peak Base Current		Івм	200	mA

## Thermal Characteristics (@TA = +25°C, unless otherwise specified.)

Characteristic		Symbol	Value	Unit
Power Dissipation	(Note 5)	PD	200	mW
Thermal Resistance, Junction to Ambient	(Note 5)	Reja	625	°C/W
Thermal Resistance, Junction to Case	(Note 5)	Rejc	115	°C/W
Operating and Storage Temperature Range		TJ, TSTG	-65 to +150	°C

### ESD Ratings (Note 6)

Characteristic	Symbol	Value	Unit	JEDEC Class
Electrostatic Discharge - Human Body Model	ESD HBM	4,000	V	3A
Electrostatic Discharge - Charged Device Model	ESD CDM	1,000	V	C3
Electrostatic Discharge - Machine Model	ESD MM	400	V	С

Notes:

# **Thermal Characteristic and Derating Information**

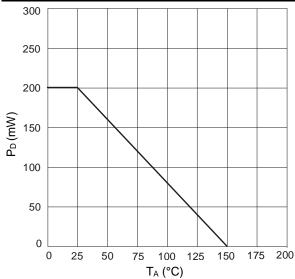


Figure 1. P<sub>D</sub> v T<sub>A</sub>

<sup>5.</sup> For a device mounted on minimum recommended pad layout 1oz weight copper that is on a single-sided FR4 PCB; device is measured under still air conditions whilst operating in a steady-state.

<sup>6.</sup> Refer to JEDEC specification JESD22-A114 and JESD22-A115.



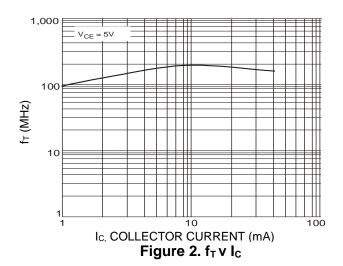
# **Electrical Characteristics** (@T<sub>A</sub> = +25°C, unless otherwise specified.)

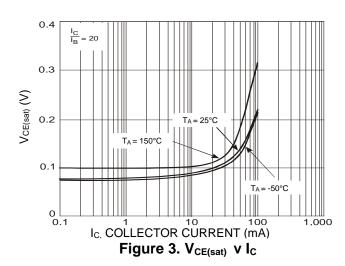
Characteristic					Min	Тур	Max	Unit	Test Condition	
Collector-Base Breakdown Voltage		BC846BWQ		BV <sub>CBO</sub> 80		_		V	I <sub>C</sub> = 100µA	
Concolor Baco Broakaciini	ronago	BC847BWQ/BC847CWQ		ВУСВО	50			V	10 = 100μΑ	
Collector-Emitter Breakdowr	n Voltage		16BWQ	BVceo	65	_	_	V	Ic = 10mA	
(Note 7)		BC847BWC	Q/BC847CWQ	DVCEO	45			•	IC = TOTILA	
Emitter-Base Breakdown Vo	ltage			BV <sub>EBO</sub>	6	_	_	V	I <sub>E</sub> = 100μA	
DC Current Gain (Note 7)	Current (	Gain Group	В	_	200	290	450	_	V <sub>CE</sub> = 5.0V, I <sub>C</sub> = 2.0mA	
Do odirent dam (Note 1)	Ourient	Jain Gloup	С		420	520	800		VCE = 5.0V, IC = 2.0IIIA	
Collector Cutoff Current				I <sub>CBO</sub>			20	nA	VcB = 30V	
Collector Catoli Carrent				ICBO			5	μΑ	$V_{CB} = 30V, T_A = +150^{\circ}C$	
Callantan Fraittan Caturation	\/=lt===	lata 7)		V <sub>CE(sat)</sub>	_	90	250	mV	$I_C = 10mA$ , $I_B = 0.5mA$	
Collector-Emitter Saturation	voltage (r	Note 7)				200	600	IIIV	Ic = 100mA, I <sub>B</sub> = 5.0mA	
Base-Emitter Turn-on Voltage	no (Noto 7)			Voc	580	660	700	mV	$I_C = 2mA$ , $V_{CE} = 5V$	
Dase-Emiller Turr-on Voltag	ge (Note 7)	1		V <sub>BE(on)</sub>	_	_	770	IIIV	Ic = 10mA, VcE = 5V	
Base-Emitter Saturation Vol-	tago (Noto	7)		1/		700	_   mV		$I_C = 10mA$ , $I_B = 0.5mA$	
Dase-Limiter Saturation voi	lage (Note	(1)		V <sub>BE(sat)</sub>	_	900		IIIV	$I_C = 100 \text{mA}, I_B = 5 \text{mA}$	
Output Capacitance				Cobo		3	4.5	pF	V <sub>CB</sub> = 10V, f = 1.0MHz	
Transition Frequency			f⊤	100	300		MHz	V <sub>CE</sub> = 5V, I <sub>C</sub> = 10mA f = 100MHz		
Noise Figure				NF	_	_	10	dB	$V_{CE} = 5V, \ I_{C} = 200\mu A$ $R_{S} = 2k\Omega, \ f = 1kHz$ $\Delta f = 200Hz$	

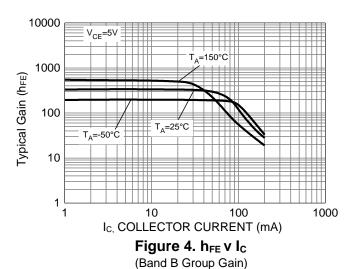
Note: 7. Measured under pulsed conditions. Pulse width  $\leq 300 \mu s$ . Duty cycle  $\leq 2\%$ .

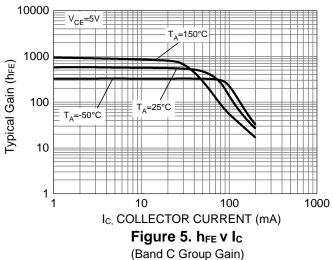


# Typical Electrical Characteristics (@TA = +25°C, unless otherwise specified.)







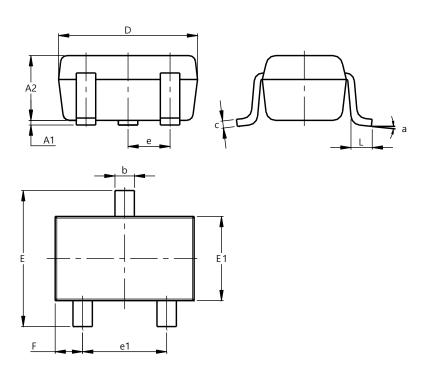




# **Package Outline Dimensions**

Please see http://www.diodes.com/package-outlines.html for the latest version.

### **SOT323**

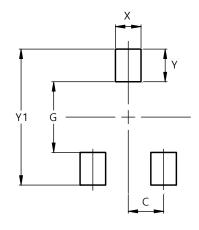


SOT323							
Dim	Min	Min Max Typ					
<b>A</b> 1	0.00	0.10	0.05				
A2	0.90	1.00	0.95				
b	0.25	0.40	0.30				
C	0.10	0.18	0.11				
D	1.80	2.20	2.15				
Е	2.00	2.20	2.10				
E1	1.15	1.35	1.30				
е	C	).650 B	SC				
e1	1.20	1.40	1.30				
F	0.375	0.475	0.425				
L	0.25	0.40	0.30				
а	0°	8°					
All Dimensions in mm							

# **Suggested Pad Layout**

Please see http://www.diodes.com/package-outlines.html for the latest version.

### **SOT323**



Dimensions	Value (in mm)
C	0.650
G	1.300
Х	0.470
Y	0.600
Y1	2.500



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